Quad 2-input NAND gate BU4011B / BU4011BFV

The BU4011B, BU4011BF, and BU4011BFV are dual-input positive logic NAND gates.

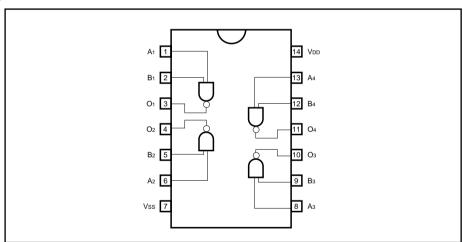
Four circuits are contained on a single chip. An inverter-based buffer has been added to the gate output, enabling improved input / output propagation characteristics, and an increased load capacitance minimizes fluctuation in propagation time.

Features

- 1) Low power dissipation.
- 2) Wide range of operating power supply voltage.
- 3) High input impedance.

- 4) High fan-out.
- 5) Direct drive of 2 L-TTL inputs and 1 LS-TTL input.

Block diagram



● Absolute maximum ratings (Vss = 0V, Ta = 25°C)

Parameter	Symbol	Limits	Unit
Power supply voltage	V _{DD}	- 0.3 ~ + 18	V
Power dissipation	Pd	1000 (DIP), 450 (SOP) 350 (SSOP-B14)	mW
Operating temperature	Topr	- 40 ~ + 85	°C
Storage temperature	Tstg	− 55 ~ + 150	°C
Input voltage	Vin	- 0.3 ~ VDD + 0.3	V



Electrical characteristics

DC characteristics (unless otherwise noted, Vss = 0V, Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit		Conditions	Measurement circuit
						V _{DD} (V)	Conditions	
Input high-level voltage	ViH	3.5	_	_	V	5	_	Fig. 1
		7.0	_	_		10		
		11.0	_	_		15		
Input low-level voltage	VıL	_	_	1.5	V	5	_	Fig. 1
		_	_	3.0		10		
		_	_	4.0		15		
Input high-level current	Іін	_	_	0.3	μА	15	Vін = 15V	Fig. 1
Input low-level current	Iι∟	T —	_	- 0.3	μА	15	VIL = 0V	Fig. 1
	Vон	4.95	_	_		5	Io = 0mA	Fig. 1
Output high-level voltage		9.95	_	_	V	10		
		14.95	_	_		15		
Output low-level voltage	Vol	T —	_	0.05	V	5	lo = 0mA	Fig. 1
		_	_	0.05		10		
		_	_	0.05		15		
Output high-level current	Іон	- 0.16	_	_	mA	5	Vон = 4.6V	Fig. 1
		- 0.4	_	_		10	Vон = 9.5V	
		- 1.2	_	_		15	Vон = 13.5V	
Output low-level current	loL	0.44	_	_	mA	5	Vol = 0.4V	Fig. 1
		1.1	_	_		10	Vol = 0.5V	
		3.0	_	_		15	Vol = 1.5V	
Static current dissipation	loo	_	_	1	μА	5	VI = VDD or GND	_
		_	_	2		10		
		_	_	4		15		

Switching characteristics (unless otherwise noted, Ta = 25°C, Vss = 0V, CL = 50pF)

Parameter	Symbol	Min.	Тур.	Max.	Unit.	V _{DD} (V)	Conditions	Measurement circuit
Output rise time	tтьн	_	180	360	ns	5	_	Fig. 2
		_	90	180		10		
		_	65	130		15		
Output fall time	tтн∟	_	100	200	ns	5	_	Fig. 2
		_	50	100		10		
		_	40	80		15		
"L" to "H" Propagation delay time	tрLн	_	90	180	ns	5	_	Fig. 2
		_	50	100		10		
		_	40	80		15		
"H" to "L" Propagation delay time	t _{PHL}	_	90	180	ns	5	_	Fig. 2
		_	50	100		10		
		_	40	80		15		
Input capacitance	Cin	_	5	_	pF	_	_	_

Measurement circuits

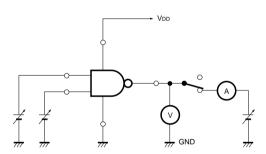


Fig. 1 DC characteristics

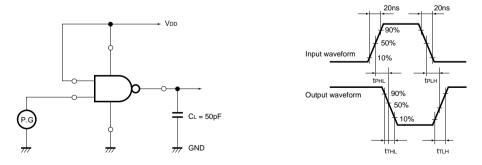


Fig. 2 Switching characteristics

Electrical characteristic curve

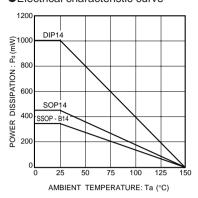
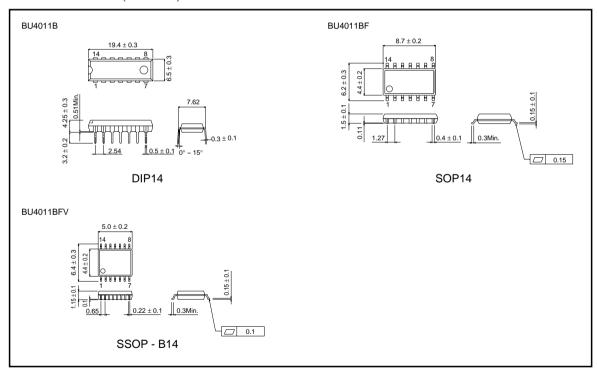


Fig. 3 Power dissipation vs. Ta

●External dimensions (Units: mm)



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